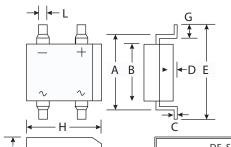


DF005S THRU DF10S

CURRENT 1.0 Ampere VOLTAGE 50 to 1000 Volts

Features

- · Glass Passivated Die Construction
- · Diffused Junction
- · Low Forward Voltage Drop, High Current Capability
- · Surge Overload Rating to 50A Peak
- · Designed for Surface Mount Application
- · Plastic Material UL Flammability Classification 94V-0



| K→|

Mechanical Data

· Case: Molded Plastic

· Terminals : Solder Plated Leads,

Solderable per MIL-STD-202, Method 208

Polarity: As Marked on Case
Approx Weight: 0.38 grams
Mounting Position: Any
Marking: Type Number

DF-S								
Dim	Min	Max						
Α	7.40	7.90						
В	6.20	6.50						
С	0.22	0.30						
D	0.076	0.33						
Е		10.40						
G	1.02	1.53						
Н	8.13	8.51						
J	2.40	2.60						
K	5.00	5.20						
L	1.00	1.20						
All Dimensions in mm								

Maximum Ratings And Electrical Characteristics

(Ratings at 25 $^{\circ}$ C ambient temperature unless otherwise specified, Single phase, half wave 60Hz, resistive or inductive load. For capacitive load, derate by 20%)

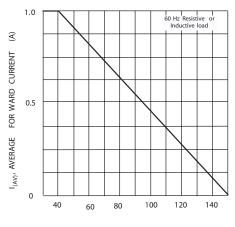
		Symbols	DF 005S	DF 01S	DF 02S	DF 04S	DF 06S	DF 08S	DF 10S	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		Vrmm Vrwm Vr	50	100	200	400	600	800	1000	Volts
RMS Reverse voltage		Vrms	35	70	140	280	420	560	700	Volts
Average Rectified Output Current @ TA=40°C		lo	1.0						Amp	
Non-Repetitive Peak Forward Surge Current, 8.3ms single half-sine-wave superimposed on rated load (JEDEC method)		lfsm	50						Amp	
Forward Voltage (per element)	@ IF=1.0 A	VFM	1.1					Volts		
Peak Reverse Current at Rated DC Blocking Voltage (per element)	@ Ta=25 ℃	- Irm	10					μΑ		
	@ Ta=100 ℃		500							
I ² t Rating for Fusing (t<8.3ms)		l ² t	10.4					A ² s		
Typical Junction Capacitance per element (Note 1)		Cj				25				pF
Typical Thermal Resistance, Junction to Ambient (Note 2)		R θ ја	40						°C/W	
Operating and Storage Temperatur	ture Range Tj TsTG		-65 to +150					°C		

Notes

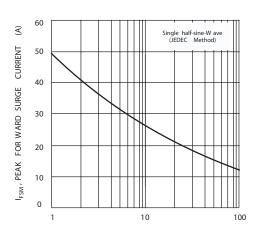
- (1) Measured at 1.0MHz and Applied Reverse Voltage of 4.0V DC.
- (2) Thermal Resistance, junction to ambient, measured on PC board with 5.02mm (0.03mm thick) land areas.



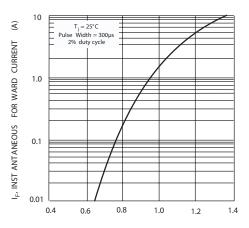
RATING AND CHARACTERISTIC CURVES DF005S THRU DF10S



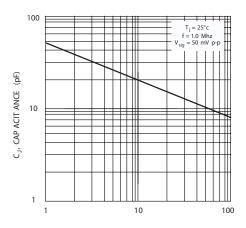
T_A, AMBIENT TEMPERA TURE (°C) Fig. 1 Output Current Derating Curve



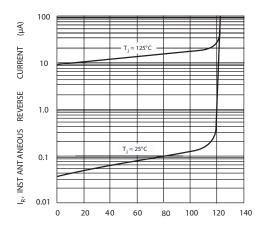
NUMBER OF CYCLES AT 60 Hz Fig. 3 Max Non-Repetitive Peak Forward Surge Current



 $\rm V_{\rm F}$, INST ANTANEOUS FOR WARD VOLTAGE (V) Fig. 2 Typ Forward Characteristics (per element)



 $\label{eq:VR} {\rm V_R,\,REVERSE} \quad {\rm VOL\,TAGE} \ \ ({\rm V})$ Fig. 4 Typ Junction Capacitance (per element)



PERCENT OF RATED PEAK REVERSE VOLTAGE (%) Fig. 5 Typ Reverse Characteristics (per element)